WHAT IS CLAIMED IS:

- 1. A lithographic apparatus comprising:
- an illumination system that provides a beam of radiation;
- a support structure that supports a patterning structure, the patterning structure configured to impart the beam of radiation with a pattern in its cross-section;
 - a substrate support that supports a substrate;
- a projection system that projects the patterned beam onto a target portion of the substrate; and
- a debris-mitigation system that mitigates debris particles which are formed during use of at least a part of the lithographic apparatus, wherein the debris-mitigation system is arranged to apply a magnetic field so that at least charged debris particles are mitigated.
- 2. A lithographic apparatus according to claim 1, wherein the debris-mitigation system comprises a plurality of debris-trapping surfaces.
- 3. A lithographic apparatus according to claim 2, wherein the debris-mitigation system is further arranged to apply the magnetic field such that, in use, the charged particles are moved substantially towards at least one of the plurality of debris-trapping surfaces.
- 4. A lithographic apparatus according to claim 1, wherein the debris-mitigation system is further arranged to apply the magnetic field such that, in use, at least some of the charged debris particles spiralize.
- 5. A lithographic apparatus according to claim 1, wherein the debris-mitigation system comprises at least one solenoid for applying the magnetic field.
- 6. A lithographic apparatus according to claim 1, wherein the debris-mitigation system is further arranged to switch the magnetic field alternatingly on and off.

- 7. A lithographic apparatus according to claim 1, wherein the debris-mitigation system is further arranged to apply a gradient to the magnetic field.
- 8. A lithographic apparatus according to claim 1, wherein the debris-mitigation system is further arranged to apply the magnetic field dynamically with a predetermined frequency.
- 9. A lithographic apparatus according to claim 1, wherein the debris-mitigation system comprises at least two solenoids which are substantially coaxially aligned, wherein a first one of the at least two solenoids has a diameter which differs from the diameter of a second one of the at least two solenoids.
- 10. A lithographic apparatus according to claim 1, wherein the debris mitigation system is further arranged to induce, in use, within a group of the debris particles, a current such that at least charged debris particles of that group deflect under influence of a force which has a direction perpendicular to a component of the magnetic field and perpendicular to a component of the electric current induced.
- 11. A debris-mitigation system for mitigating debris particles within a lithographic apparatus, wherein the debris-mitigation system is arranged to apply a magnetic field so that at least charged debris particles are mitigated.
- 12. A debris-mitigation system according to claim 11, wherein the debris-mitigation system further comprises a plurality of debris-trapping surfaces.
- 13. A debris-mitigation system according to claim 12, wherein the debrismitigation system is further arranged to apply the magnetic field such that, in use, the charged

particles are moved substantially towards at least one of the plurality of debris-trapping surfaces.

- 14. A debris-mitigation system according to claim 11, wherein the debris-mitigation system comprises at least one solenoid for applying the magnetic field.
- 15. A debris-mitigation system according to claim 11, wherein the debris-mitigation system is further arranged to switch the magnetic field alternatingly on and off.
- 16. A debris-mitigation system according to claim 11, wherein the debrismitigation system is further arranged to apply a gradient to the magnetic field.
- 17. A debris-mitigation system according to claim 11, wherein the debrismitigation system is further arranged to apply the magnetic field dynamically with a predetermined frequency.
- 18. A debris-mitigation system according to claim 11, wherein the debrismitigation system comprises at least two solenoids which are substantially coaxially aligned, wherein a first one of the at least two solenoids has a diameter which differs from the diameter of a second one of the at least two solenoids.
- 19. A debris-mitigation system according to claim 11, wherein the debris mitigation system is further arranged to induce, in use, within a group of the debris particles an electric current such that at least charged debris particles of that group deflect under influence of a force which has a direction perpendicular to a component of the magnetic field and perpendicular to a component of the electric current induced.

- 20. A source for producing EUV radiation, comprising a debris-mitigation system that mitigates debris particles which are formed during production of EUV radiation, wherein the debris-mitigation system is arranged to apply a magnetic field so that at least charged debris particles are mitigated.
- 21. A source according to claim 20, wherein the debris-mitigation system further comprises a plurality of debris-trapping surfaces.
- 22. A source according to claim 20, wherein the debris-mitigation system is further arranged to apply the magnetic field such that, in use, the charged particles are moved substantially towards at least one of the plurality of debris-trapping surfaces.
- 23. A source according to claim 20, wherein the debris-mitigation system comprises at least one solenoid for applying the magnetic field.
- 24. A source according to claim 20, wherein the debris-mitigation system is further arranged to switch the magnetic field alternatingly on and off.
- 25. A source according to claim 20, wherein the debris-mitigation system is further arranged to apply a gradient to the magnetic field.
- 26. A source according to claim 20, wherein the debris-mitigation system is further arranged to apply the magnetic field dynamically with a predetermined frequency.
- 27. A source for producing EUV radiation according to claim 20, wherein the debris-mitigation system comprises at least two solenoids which are substantially coaxially aligned, wherein a first one of the at least two solenoids has a diameter which differs from the diameter of a second one of the at least two solenoids.

- 28. A source for producing EUV radiation according to claim 20, wherein the debris mitigation system is further arranged to induce, in use, within a group of the debris particles an electric current such that at least charged debris particles of that group deflect under influence of a force which has a direction perpendicular to a component of the magnetic field and perpendicular to a component of the electric current induced.
- 29. A method for mitigating debris as produced during use of at least a part of a lithographic apparatus, the method comprising:

applying a magnetic field so that at least charged debris particles are mitigated.

- 30. A method according to claim 29, wherein the debris-mitigation system further comprises a plurality of debris-trapping surfaces.
- 31. A method according to claim 30, wherein the magnetic field is applied such that, in use, the charged particles are moved substantially towards at least one of the number of debris-trapping surfaces.
- 32. A method according to claim 29, wherein the debris-mitigation system comprises at least one solenoid for applying the magnetic field.
- 33. A method according to claim 29, wherein the magnetic field is alternatingly switched on and off.
- 34. A method according to claim 29, wherein a gradient is applied to the magnetic field.
- 35. A method according to claim 29, wherein the magnetic field is applied dynamically with a predetermined frequency.

36. A method according to claim 29, wherein the debris-mitigation system comprises at least two solenoids which are substantially coaxially aligned, wherein a first one of the at least two solenoids has a diameter which differs from the diameter of a second one of the at least two solenoids.

٠;

37. A method according to claim 29, wherein within a group of the desired particles an external electric current is induced such that at least charged debris particles deflect under influence of a force which has a direction perpendicular to a component of the magnetic field and perpendicular to a component of the electric current externally induced.

38. A lithographic apparatus comprising:

an EUV radiation generator that produces EUV radiation, wherein charged particle debris is generated as a byproduct of EUV radiation production;

a support structure that supports a patterning structure to be impinged by a beam of said EUV radiation, the patterning structure configured to impart the beam of radiation with a pattern in its cross-section;

- a substrate support that supports a substrate;
- a projection system that projects the patterned beam onto a target portion of the substrate; and
 - a magnetic field generator that interacts with said charged debris particles.
- 39. A lithographic apparatus according to claim 38, wherein the debris-mitigation system further comprises a plurality of debris trapping surfaces, and the magnetic field generator generates a magnetic field that causes the charged debris particles to move towards the plurality of debris trapping surfaces.
- 40. A lithographic apparatus according to claim 38, wherein the magnetic field generator comprises at least one solenoid.

41. A lithographic method comprising:

generating a beam of EUV radiation, wherein production of said EUV radiation causes generation of charged particle debris as a byproduct;

patterning said beam of EUV radiation;

projecting said patterned beam of EUV radiation onto a substrate; and generating a magnetic field to interact with said charged debris particles.